

GMPB01 Silicon Pressure Sensor

General Introduction

GMPB01 is a gauge type silicon pressure sensor especially designed for applications requiring highly-precision pressure measurement from 0 to 40kPa. The pressure sensor is based on the industry-recognized piezo-resistive technology featuring long-term stability and EMC robustness. Both DIP or SOP type of packages are available.

Features

O Operation range: 0~40kPa

O SOP6 or DIP6 package

O Gauge type sensor

O Low cost

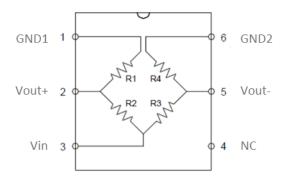
Applications

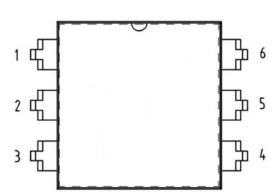
O Medical instrumentation

O Pressure gauge

O Industrial sensor

O Home appliance











GMPB01-0S

GMPB01-0P

GMPB01-0B



Pin Descriptions

Pin#	Name	Description
1	GND1	Ground pin 1
2	Vout+	Signal out +
3	Vin	Power supply in
4	NC	No connection
5	Vout-	Signal out -
6	GND2	Ground pin 2

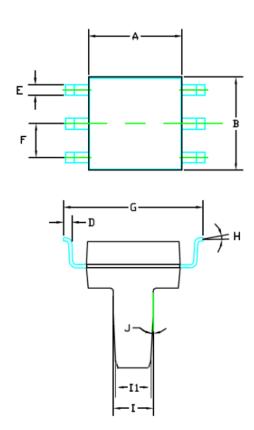
Specifications

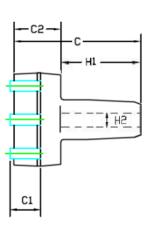
		104110110			
Parameter	Condition	Min.	Тур.	Max.	Unit
Excitation voltage		_	5	10	V
Bridge impedance		4	5	6	$\mathrm{k}\Omega$
Span		0	_	40	kPa
Full scale span	Vin=5V	60	75	90	mV
Offset	Vin=5V	-15	0	15	mV
TC resistance		1600	2000	2400	ppm/°C
m c	Constant voltage	-0.27	-0.22	-0.17	%V _{FS} /°C
TC span	Constant current	-0.03	_	0.03	%V _{FS} /°C
TC offset		-0.08	_	0.08	$%V_{\mathrm{FS}}$
Linearity	Best fit straight line	-0.3	_	0.3	$%V_{\mathrm{FS}}$
Pressure hysteresis		-0.1	0.05	0.1	$%V_{\mathrm{FS}}$
Temperature hysteresis		-0.3	_	0.3	$%V_{\mathrm{FS}}$
Proof pressure				2X	FS
Burst pressure				3X	FS
Operating temperature		-20		+85	°C
Storage temperature		-40		+125	°C



Package

GMPB01-0S (SOP6 Tube)



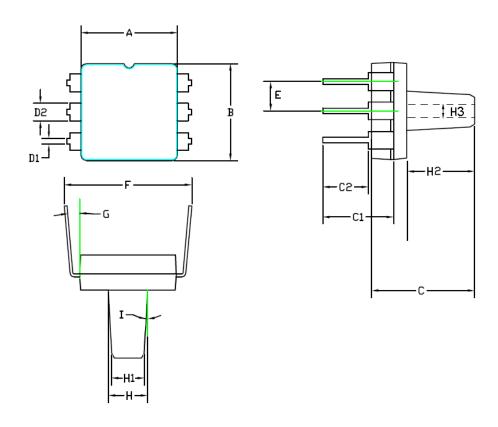


Symbol	Dimension (mm)	Symbol	Dimension (mm)
A	7.0	G	10.3
В	7.0	Н	0-8°
С	9.5	H1	6.0
C1	2.1-2.4	H2	1.2
C2	3.5	I	3.2
D	0.7	I1	2.6
Е	0.8	J	0-3°
F	2.54		



Package

GMPB01-0P (DIP Top Tube)

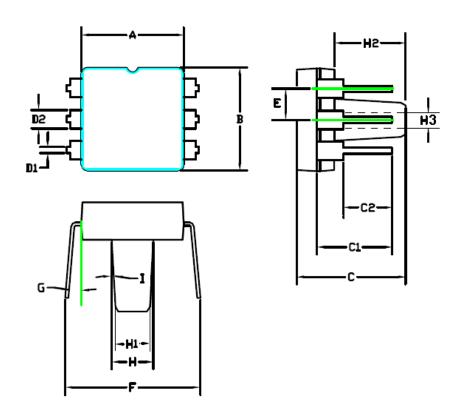


Symbol	Dimension (mm)	Symbol	Dimension (mm)
A	8.4	F	10.25~11.75
В	8.4	G	0-9°
С	9.0	Н	3.4
C1	6.2	H1	2.8
C2	4.0	H2	5.88
D1	0.42-0.56	Н3	1.2
D2	1.5	I	3°
Е	2.54		



Package

GMPB01-0B (DIP Bottom Tube)



Symbol	Dimension (mm)	Symbol	Dimension (mm)
A	8.4	F	10.25~11.75
В	8.4	G	0-9°
С	9.0	Н	3.4
C1	6.2	H1	2.8
C2	4.0	H2	5.88
D1	0.42-0.56	Н3	1.2
D2	1.5	I	3°
E	2.54		



Characteristic curve

Test condition: 5V, 25°C

